

Bipolar Transistor

(-)160 V, (-)1.5 A, Low V_{CE}(sat), (PNP) NPN Single PCP

2SA1419, 2SC3649

Features

- Adoption of FBET, MBIT Processes
- High Breakdown Voltage and Large Current Capacity
- Ultrasmall Size Making it Easy to Provide High-density, Small-sized Hybrid IC's

Specifications

(): 2SA1419

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

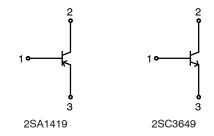
Symbol	Parameter	Conditions	Ratings	Unit
V _{CBO}	Collector-to-Base Voltage	-	(-)180	V
V _{CEO}	Collector-to-Emitter Voltage	-	(-)160	V
V_{EBO}	Emitter-to-Base Voltage	-	(–)6	V
I _C	Collector Current	-	(–)1.5	Α
I _{CP}	Collector Current (Pulse)	-	(-)2.5	Α
Pc	Collector Dissipation	-	500	mW
		When mounted on ceramic substrate (250 mm ² x 0.8 mm)	1.5	V
Tj	Junction Temperature	-	150	°C
Tstg	Storage Temperature	-	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

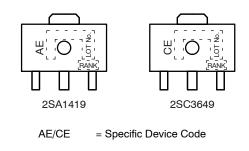


- 1. Base
- Collector
 Emitter
- SOT-89 / PCP-1 CASE 419AU

ELECTRICAL CONNECTIONS



MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Symbol	Parameter	Conditions	Ratings		Unit	
			Min	Тур	Max	
I _{CBO}	Collector Cutoff Current	V _{CB} = (-)120 V, I _E = 0 A	-	-	(-)1	μΑ
I _{EBO}	Emitter Cutoff Current	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)1	μΑ
h _{FE} 1	DC Current Gain	$V_{CE} = (-)5 \text{ V}, I_{C} = (-)100 \text{ mA}$	100*	-	400*	
h _{FE} 2		V _{CE} = (-)5 V, I _C = (-)10 mA	80	-	-	
f _T	Gain-Bandwidth Product	$V_{CE} = (-)10 \text{ V}, I_{C} = (-)50 \text{ mA}$	-	120	-	MHz
Cob	Output Capacitance	V _{CB} = (-)10 V, f = 1 MHz	-	(22)14	-	pF
V _{CE} (sat)	Collector-to-Emitter Saturation Voltage	I _C = (-)500 mA, I _B = (-)50 mA	-	(-200) 130	(-500) 450	mV
V _{BE} (sat)	Base-to-Emitter Saturation Voltage	I _C = (-)500 mA, I _B = (-)50 mA	-	(-)0.85	(-)1.2	V
V _{(BR)CBO}	Collector-to-Base Breakdown Voltage	I _C = (-)10 μA, I _E = 0 A	(-)180	-	-	V
V _{(BR)CEO}	Collector-to-Emitter Breakdown Voltage	I _C = (-)1 mA, R _{BE} = ∞	(-)160	-	-	V
V _{(BR)EBO}	Emitter-to-Base Breakdown Voltage	I _E = (-)10 μA, I _C = 0 A	(-)6	-	-	V
t _{on}	Turn-ON Time	See specified Test Circuit	-	(40) 40	-	ns
t _{stg}	Storage Time		-	(0.7) 1.2	-	μs
t _f	Fall Time		-	(40) 80	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

* The 2SA1419 / 2SC3649 are classified by 100 mA h_{FE} as follows:

Rank
 R
 S
 T

 h_{FE}
 100 to 200
 140 to 280
 200 to 400

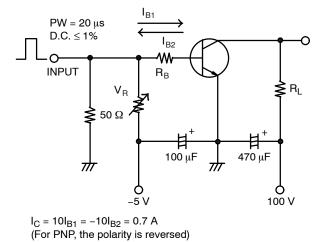
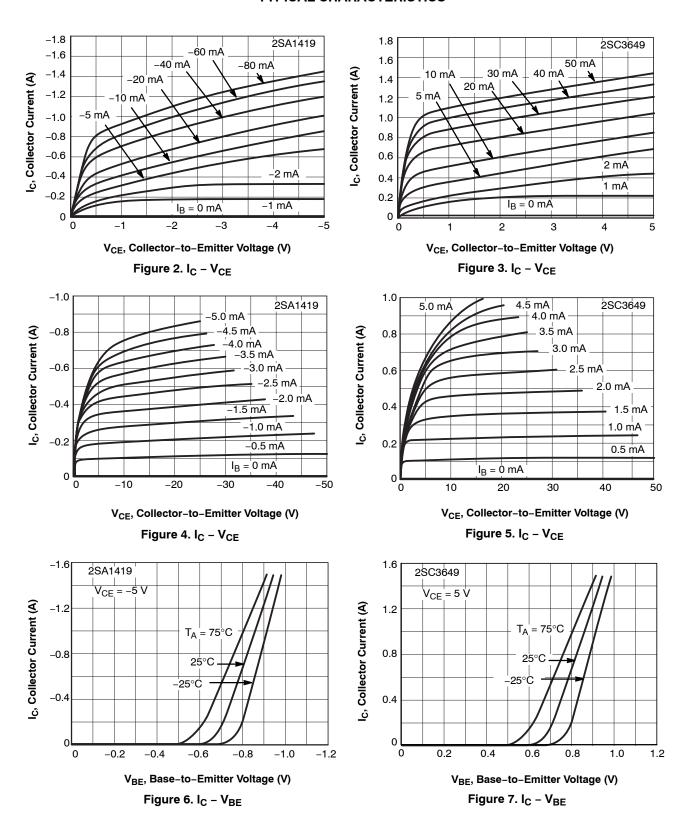


Figure 1. Switching Time Test Circuit

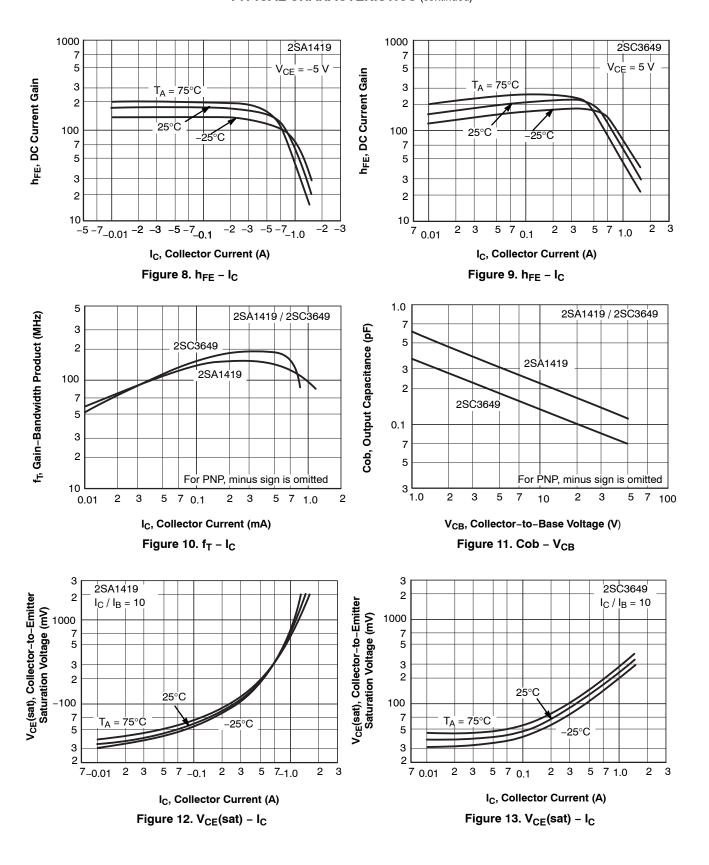
2SA1419, 2SC3649

TYPICAL CHARACTERISTICS



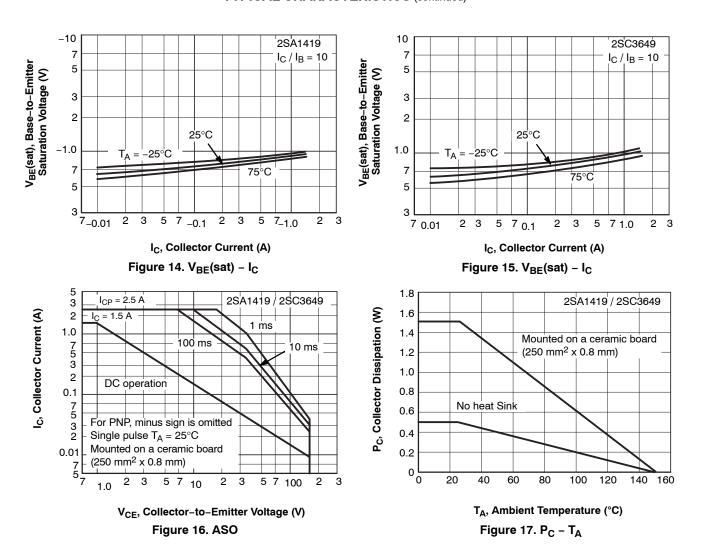
2SA1419, 2SC3649

TYPICAL CHARACTERISTICS (continued)



2SA1419, 2SC3649

TYPICAL CHARACTERISTICS (continued)



ORDERING INFORMATION

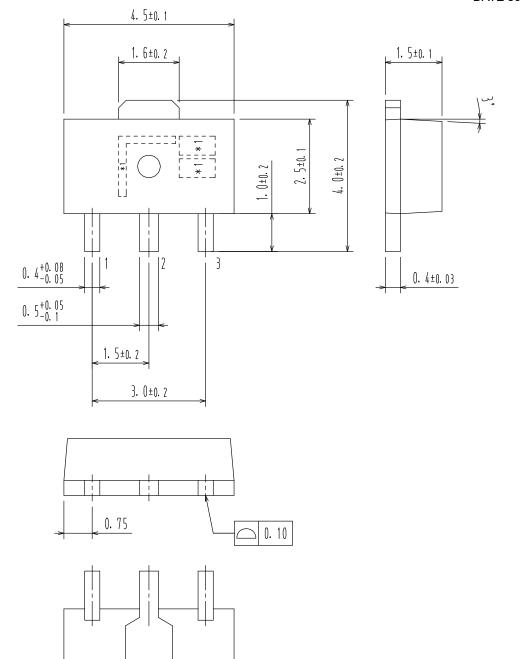
Device	Package	Shipping [†]
2SA1419S-TD-E	SOT-89 / PCP-1 (Pb-Free)	1000 / Tape & Reel
2SA1419T-TD-E	SOT-89 / PCP-1 (Pb-Free)	1000 / Tape & Reel
2SA1419T-TD-H	SOT-89 / PCP-1 (Pb-Free, Halide Free)	1000 / Tape & Reel
2SC3649S-TD-E	SOT-89 / PCP-1 (Pb-Free)	1000 / Tape & Reel
2SC3649S-TD-H	SOT-89 / PCP-1 (Pb-Free & Halogen Free)	1000 / Tape & Reel
2SC3649T-TD-E	SOT-89 / PCP-1 (Pb-Free)	1000 / Tape & Reel
2SC3649T-TD-H	SOT-89 / PCP-1 (Pb-Free & Halogen Free)	1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SOT-89 / PCP-1 CASE 419AU ISSUE O

DATE 30 APR 2012



DOCUMENT NUMBER:	98AON79746E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOT-89 / PCP-1		PAGE 1 OF 1	

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

<u>2SC3649S-TD-H</u> <u>2SC3649T-TD-H</u> <u>2SA1419T-TD-H</u> <u>2SA1419S-TD-H</u> <u>2SA1419S-TD-E</u> <u>2SA1419T-TD-E</u> 2SC3649S-TD-E <u>2SC3649T-TD-E</u>